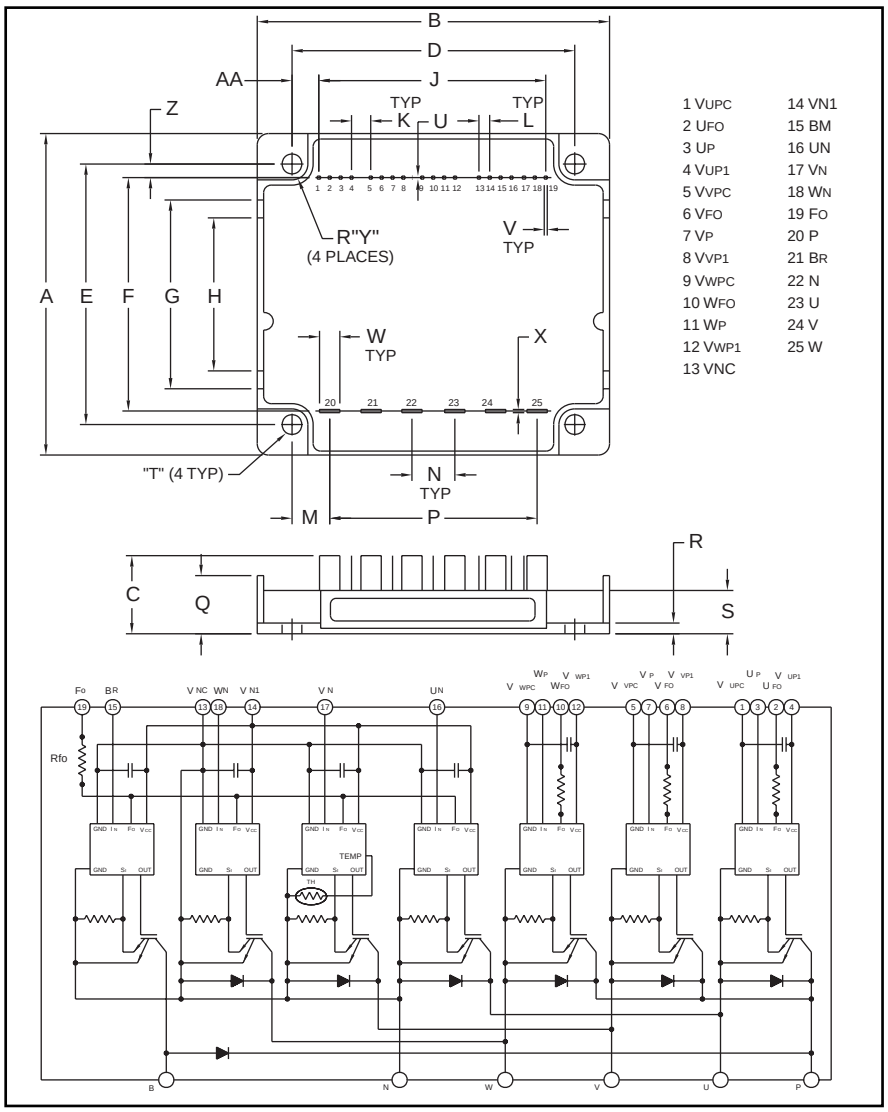
PM25RSK120

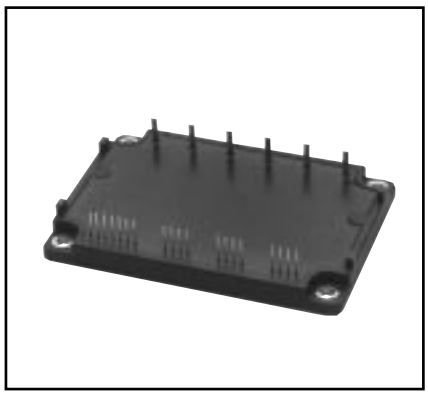
FLAT-BASE TYPE
INSULATED PACKAGE



Outline Drawing and Circuit Diagram

Dimensions	Inches	Millimeters
A	2.76±0.04	70.0±1.0
B	3.96±0.04	100.5±1.0
C	0.71±0.04	18.0±1.0
D	3.48±0.02	88.5±0.5
E	2.30±0.02	58.5±0.5
F	2.23±0.03	56.75±0.8
G	1.61	41.0
H	1.30	33.0
J	2.70±0.03	68.58±0.8
K	0.40	10.16
L	0.10±0.01	2.54±0.25
M	0.41	10.5
N	0.53±0.01	13.5±0.3

Dimensions	Inches	Millimeters
P	2.66±0.03	67.5±0.8
Q	0.49	12.4
R	0.17 Rad.	4.4 Rad.
S	0.35	8.9
T	0.18 Dia.	Dia. 4.5
U	0.02	0.4
V	0.02±0.004	0.6±0.1
W	0.08±0.004	2.0±0.1
X	0.02	0.5
Y	0.20	5.0
Z	0.04	1.02
AA	0.39	9.96



Description:
Mitsubishi Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free-wheel diode power devices.

Features:
- ☐ Complete Output Power Circuit
- ☐ Gate Drive Circuit
- ☐ Protection Logic
  - – Short Circuit
  - – Over Current
  - – Over Temperature
  - – Under Voltage

Applications:
- ☐ Inverters
- ☐ UPS
- ☐ Motion/Servo Control
- ☐ Power Supplies

Ordering Information:
Example: Select the complete part number from the table below -i.e. PM25RSK120 is a 1200V, 25 Ampere Intelligent Power Module.

Type	Current Rating Amperes	V_{CES} Volts (x 10)
PM	25	120

MITSUBISHI ELECTRIC

PM25RSK120

FLAT-BASE TYPE
INSULATED PACKAGE

Absolute Maximum Ratings, T_j = 25 °C unless otherwise specified

	Symbol	Ratings	Units
Junction Temperature	T_j	–20 to 150	°C
Storage Temperature	T_{stg}	–40 to 125	°C
Case Operating Temperature	T_C	–20 to 100	°C
Mounting Torque M4 Mounting Screws	–	0.98 ~ 1.47	N · m
Module Weight (Typical)	–	130	Grams
Supply Voltage Protected by OC and SC (V_D = 13.5 ~ 16.5V, Inverter Part, T_j = 125°C)	$V_{CC(prot.)}$	800	Volts
Isolation Voltage (Main Terminal to Baseplate, AC 1 min.)	V_{iso}	2500	Vrms

Control Sector

Supply Voltage (Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC})	V_D	20	Volts
Input Voltage (Applied between U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, U_N · V_N · W_N · B_r-V_{NC})	V_{CIN}	20	Volts
Fault Output Supply Voltage (Applied between U_{FO}-V_{UPC}, V_{FO}-V_{VPC}, W_{FO}-V_{WPC}, F_O-V_{NC})	V_{FO}	20	Volts
Fault Output Current (Sink Current at U_{FO}, V_{FO}, W_{FO} and F_O Terminal)	I_{FO}	20	mA

IGBT Inverter Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	1200	Volts
Collector Current, (T_C = 25°C)	I_C	25	Amperes
Peak Collector Current, (T_C = 25°C)	I_{CP}	50	Amperes
Supply Voltage (Applied between P-N)	V_{CC}	900	Volts
Supply Voltage, Surge (Applied between P-N)	$V_{CC\ (surge)}$	1000	Volts
Collector Dissipation	P_C	100	Watts

Brake Sector

Collector-Emitter Voltage (V_D = 15V, V_{CIN} = 15V)	V_{CES}	1200	Volts
Collector Current, (T_C = 25°C)	I_C	10	Amperes
Peak Collector Current, (T_C = 25°C)	I_{CP}	20	Amperes
Supply Voltage (Applied between P-N)	V_{CC}	900	Volts
Supply Voltage, Surge (Applied between P-N)	$V_{CC\ (surge)}$	1000	Volts
Collector Dissipation	P_C	43	Watts
Diode Forward Current	I_F	10	Amperes
Diode DC Reverse Voltage	$V_{R(DC)}$	1200	Volts

Electrical and Mechanical Characteristics, T_j = 25 °C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
Control Sector						
Over Current Trip Level Inverter Part	OC	-20°C ≤ T_j ≤ 125°C, V_D = 15V	32	58	–	Amperes
Over Current Trip Level Brake Part			15	30	–	Amperes
Short Circuit Trip Level Inverter Part	SC	-20°C ≤ T_j ≤ 125°C, V_D = 15V	–	81	–	Amperes
Short Circuit Trip Level Brake Part			–	41	–	Amperes
Over Current Delay Time	$t_{off(OC)}$	V_D = 15V	–	10	–	µs
Over Temperature Protection	OT	Trip Level	100	110	120	°C
	OT_r	Reset Level	–	90	–	°C
Supply Circuit Under Voltage Protection	UV	Trip Level	11.5	12.0	12.5	Volts
	UV_r	Reset Level	–	12.5	–	Volts
Supply Voltage	V_D	Applied between V_{UP1}-V_{UPC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}, V_{N1}-V_{NC}	13.5	15.0	16.5	Volts
Circuit Current	I_D	V_D = 15V, V_{CIN} = 15V, V_{N1}-V_{NC}	–	44	60	mA
		V_D = 15V, V_{CIN} = 15V, V_{XP1}-V_{XPC}	–	13	18	mA
Input ON Threshold Voltage	$V_{th(on)}$	Applied between	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{th(off)}$	U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, U_N · V_N · W_N · B_r-V_{NC}	1.7	2.0	2.3	Volts
PWM Input Frequency	f_{PWM}	3-ϕ Sinusoidal	5	15	20	kHz
Fault Output Current	$I_{FO(H)}$	V_D = 15V, V_{FO} = 15V	–	–	0.01	mA
	$I_{FO(L)}$	V_D = 15V, V_{FO} = 15V	–	10	15	mA
Minimum Fault Output Pulse Width	t_{FO}	V_D = 15V	1.0	1.8	–	ms

Electrical and Mechanical Characteristics, T_j = 25°C unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
IGBT Inverter Sector						
Collector-Emitter Cutoff Current	I_{CES}	$V_{CE} = V_{CES}$, V_D = 15V, T_j = 25°C	–	–	1	mA
		$V_{CE} = V_{CES}$, V_D = 15V, T_j = 125°C	–	–	10	mA
Emitter-Collector Voltage	V_{EC}	$-I_C$ = 25A, V_D = 15V, V_{CIN} = 15V	–	2.5	3.5	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 25A, T_j = 25°C	–	2.5	3.5	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 25A, T_j = 125°C	–	2.2	3.2	Volts
Inductive Load Switching Times	t_{on}	V_D = 15V, V_{CIN} = 0 ↔ 15V, V_{CC} = 600V, I_C = 25A, T_j = 125°C, Inductive Load	0.5	1.0	2.5	µs
	t_{rr}		–	0.15	0.3	µs
	$t_{C(on)}$		–	0.4	1.0	µs
	t_{off}		–	2.0	3.0	µs
	$t_{C(off)}$		–	0.7	1.2	µs
Brake Sector						
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	V_D = 15V, V_{CIN} = 0V, I_C = 10A, T_j = 25°C	–	2.8	3.8	Volts
		V_D = 15V, V_{CIN} = 0V, I_C = 10A, T_j = 125°C	–	2.5	3.5	Volts
Diode Forward Voltage	V_{FM}	$-I_C$ = 15A, V_D = 15V, V_{CIN} = 15V	–	2.5	3.5	Volts
Collector-Emitter Cutoff Current	I_{CES}	$V_{CE} = V_{CES}$, V_D = 15V, T_j = 25°C	–	–	1	mA
		$V_{CE} = V_{CES}$, V_D = 15V, T_j = 125°C	–	–	10	mA

Thermal Characteristics

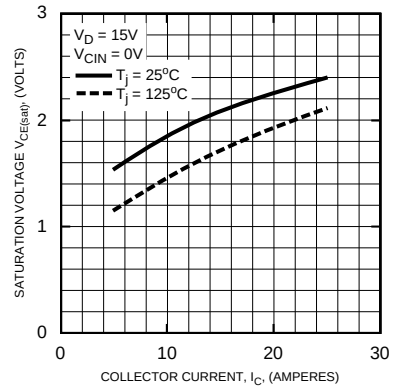
Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{th(j-c)Q}$	Each Inverter IGBT	–	–	1.25	°C/Watt
	$R_{th(j-c)F}$	Each Inverter FWDi	–	–	3.0	°C/Watt
	$R_{th(j-c)Q}$	Each Brake IGBT	–	–	2.9	°C/Watt
	$R_{th(j-c)F}$	Each Brake FWDi	–	–	5.4	°C/Watt
Contact Thermal Resistance	$R_{th(c-f)}$	Case to Fin Per Module, Thermal Grease Applied	–	–	0.038	°C/Watt

Recommended Conditions for Use

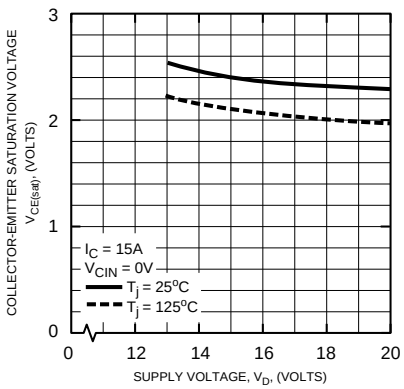
Characteristic	Symbol	Condition	Value	Units
Supply Voltage	V_{CC}	Applied across P-N Terminals	0 ~ 800	Volts
	V_D	Applied between V_{UP1}-V_{UPC}, V_{N1}-V_{NC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}	15 ± 1.5	Volts
Input ON Voltage	$V_{CIN(on)}$	Applied between U_P-V_{UPC}, V_P-V_{VPC}, W_P-V_{WPC}, $U_N \cdot V_N \cdot W_N \cdot B_r$-$V_{NC}$	0 ~ 0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$		4.0 ~ V_D	Volts
PWM Input Frequency	f_{PWM}	Using Application Circuit	5 ~ 20	kHz
Minimum Dead Time	t_{dead}	Input Signal	≥2.5	µs

Inverter Sector

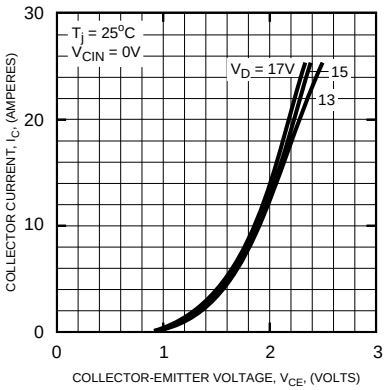
SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



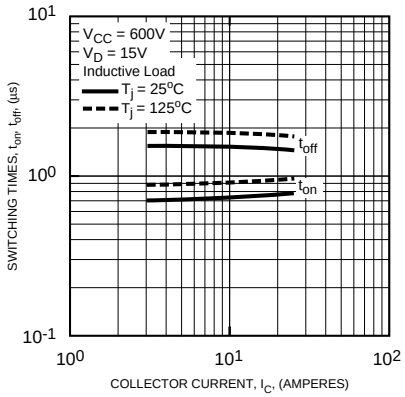
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



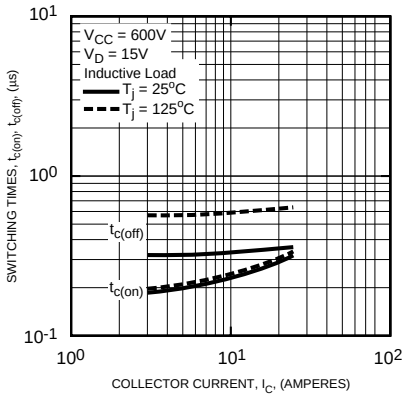
OUTPUT CHARACTERISTICS (TYPICAL)



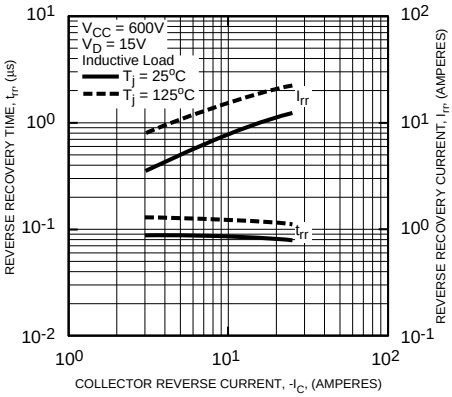
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



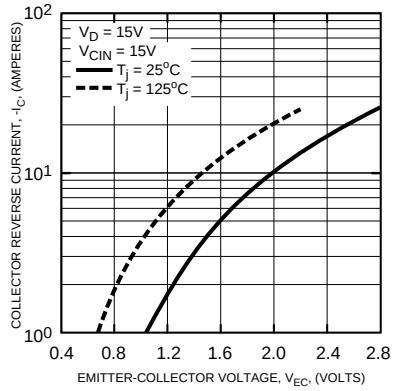
SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)



REVERSE RECOVERY CURRENT VS. COLLECTOR CURRENT (TYPICAL)

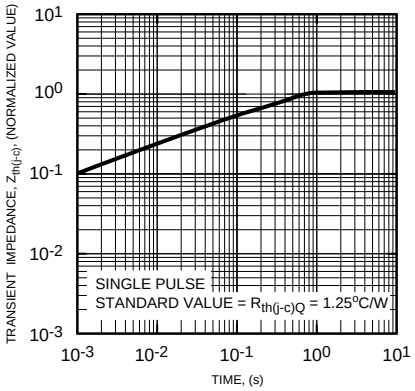


DIODE FORWARD CHARACTERISTICS (TYPICAL)

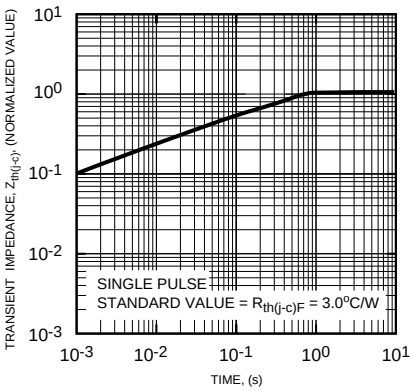


Inverter Sector

TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (Each IGBT)

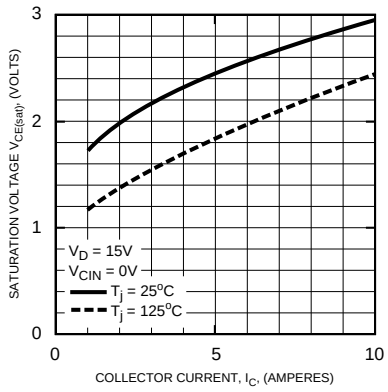


TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (Each FWDi)

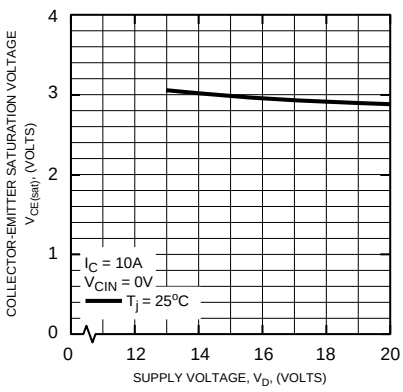


Brake Sector

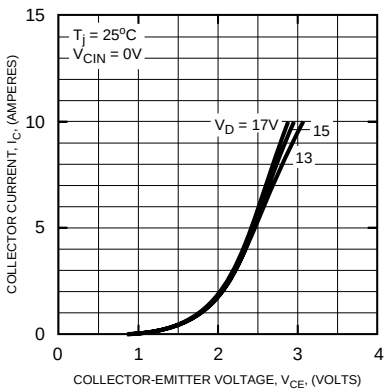
SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



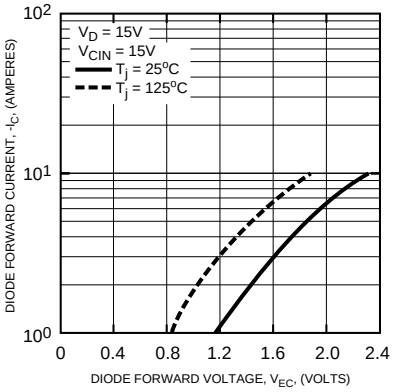
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



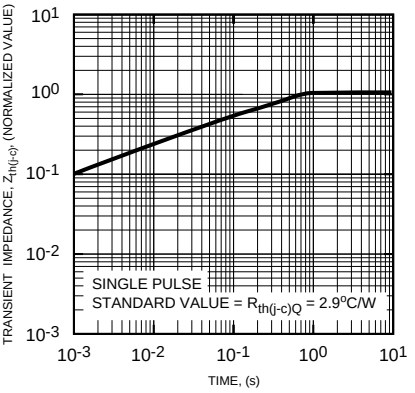
OUTPUT CHARACTERISTICS (TYPICAL)



FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (Each IGBT)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (Each FWDi)